2SC5457

Silicon NPN triple diffusion planar type

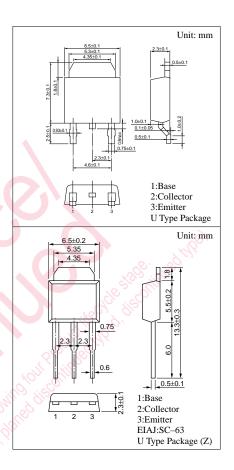
For high breakdown voltage high-speed switching

Features

- High-speed switching
- High collector to base voltage V_{CBO}
- Wide area of safe operation (ASO)
- Satisfactory linearity of foward current transfer ratio h_{FE}

Absolute Maximum Ratings (T_C=25°C)

Parameter	Symbol	Ratings	Unit	
Collector to base voltage	V _{CBO}	500	V	
C-11	V _{CES}	500	V	
Collector to emitter voltage	V _{CEO}	400	V	
Emitter to base voltage	V _{EBO}	7	V	
Peak collector current	I _{CP}	6	A	
Collector current	$I_{\rm C}$	3	A	
Base current	I _B	1.2	A	
Collector power T _C =25°C	n	30	777	
dissipation Ta=25°C	P_{C}	1.0	W	
Junction temperature	$T_{\rm j}$	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C///C/C	

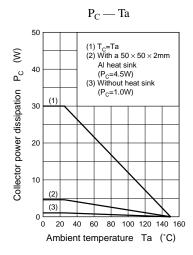


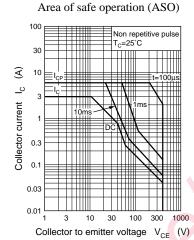
Electrical Characteristics (T_C=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 500V, I_{E} = 0$			100	μΑ
Emitter cutoff current	I _{EBO}	$V_{EB} = 5V, I_{C} = 0$			100	μА
Collector to emitter voltage	V _{CEO}	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$	400			V
Forward current transfer ratio	h _{FE1}	$V_{CE} = 5V, I_{C} = 0.1A$	10			
	h _{FE2}	$V_{CE} = 2V, I_{C} = 1.2A$	8		40	
Collector to emitter saturation voltage	V _{CE(sat)}	$I_C = 1.5A, I_B = 0.3A$			1.0	V
Base to emitter saturation voltage	V _{BE(sat)}	$I_C = 1.5A, I_B = 0.3A$			1.5	V
Transition frequency	f_T	$V_{CE} = 10V, I_C = 0.2A, f = 1MHz$		10		MHz
Turn-on time	t _{on}	I 154 I 0154 I 024			1.0	μs
Storage time	t _{stg}	$I_C = 1.5A$, $I_{B1} = 0.15A$, $I_{B2} = -0.3A$,			3.0	μs
Fall time	$t_{\rm f}$	$V_{CC} = 200V$			0.3	μs

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Power Transistors 2SC5457





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